

MSNP06065G1 650V Silicon Carbide Schottky Diode

Features

-650-Volt Schottky Rectifier

- -Shorter recovery time
- -High-speed switching possible
- -High-Frequency Operation
- -Temperature-Independent Switching Behavior
- -Extremely Fast Switching
- -Positive Temperature Coefficient on VF

Applications

- -Switch Mode Power Supplies
- Server/Telecom Power Supplies
- -Industrial Power Supplies
- -Solar Inverters

Benefits

- -Higher safety margin against overvoltage
- -Improved efficiency all load conditions
- -Increased efficiency compared to Silicon Diode alternatives
- -Reduction of Heat Sink Requirements
- -Parallel Devices Without Thermal Runaway
- -Essentialy No Switching Losses

Package

ANAXAN SHI

Type : TO-220 -2lead 1、Cathode 2、Anode



Free

Absolute Maximum Ratings T_c = 25°C unless otherwise noted

Symbol	Parameter	MSNP06065G1	Units
VRRM	Repetitive Peak Reverse Voltage	650	V
VRSM	Surge Peak Reverse Voltage	650	V
VDC	DC Blocking Voltage	650	V
IF	Continuous Forward Current @Tc=135℃	6	А
IFRM	Repetitive Peak Forward Surge Current @TC=25℃ tp = 10 ms, Half Sine Wave	40	А
IFSM	Non-Repetitive Peak Forward Surge Current @TC=25 ℃ tp= 10 ms, Half Sine Wave	60	А
IFSM	Non-Repetitive Peak Forward Surge Current @TC=25℃, tp= 10 us,pulse	520	A
Ptot	Power Dissipation @Tc=25°C @Tc=110°C	55.5 24	w
TJ , Tstg	Operating Junction and Storage Temperature	-55 to +175	°C
٧١	Isolation Blocking Voltage (leg to case)	3000	V

Package Marking						
Part Number	Top Marking	Package	Packing Method	MOQ	QTY	
MSNP06065G1	MSNP06065G1	TO-220C-2L	Tube	1000	5000	

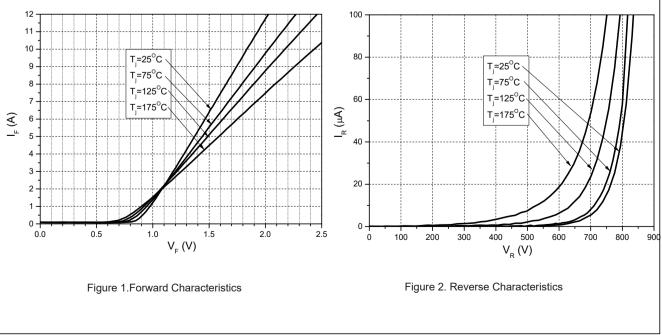
Electrical Characteristics T_c = 25° C unless otherwise noted

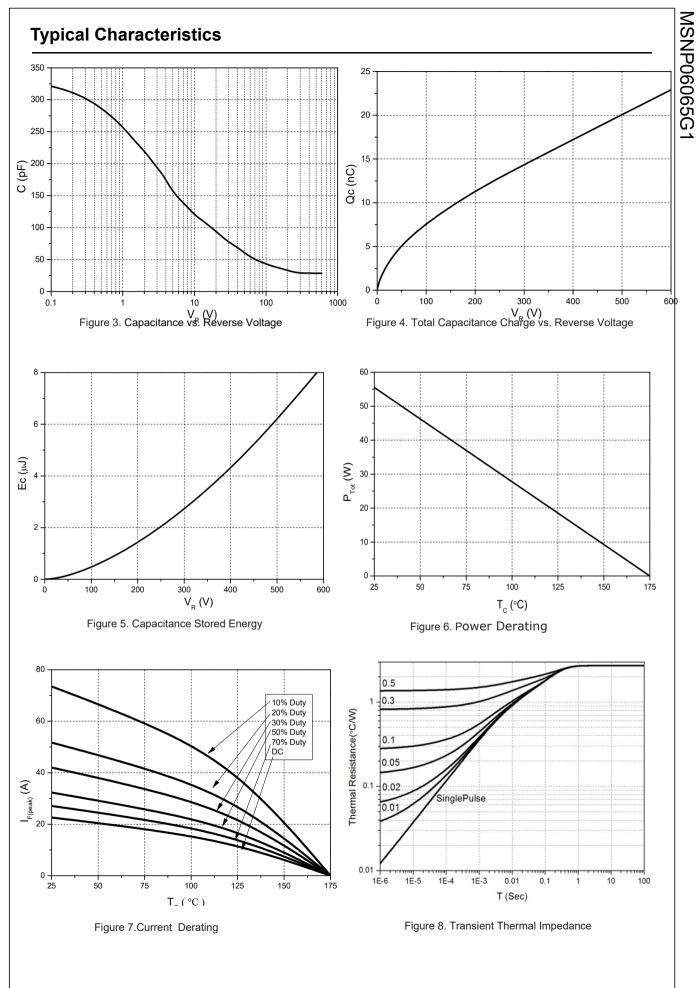
Symbol	Test Conditions	Test Conditions	Min	Тур	Мах	Unit
VF	Forward Voltage	IF=6 A, TC=25°C IF= 6 A, TC=175°C	-	1.45 1.75	1.7 2.00	V
IR	Reverse Current	VR=650V, TC=25°C VR=650V, TC=175°C	-	2 40	20 200	μA
QC	Total Capacitive Charge	VR =400V, TJ = 25° C Qc= $\int_0^{V_r} C (V) dv$	-	17	-	nC
с	Total Capacitance	VR =0V, TJ = 25°C, f=1MHz VR =200V, TJ = 25°C, f=1MHz VR =400V, TJ = 25°C, f=1MHz	-	332 33 28	-	pF
EC	Capacitance Stored Energy	VR=400V	-	4.3	-	μJ

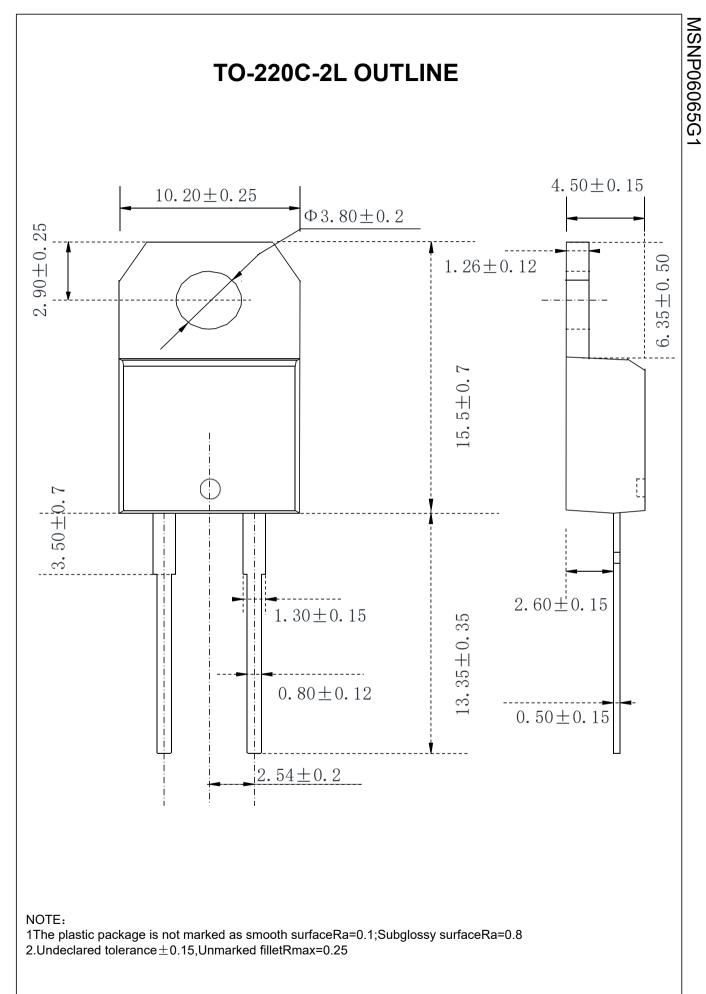
Thermal Characteristics

Symbol	Parameter	Тур	Unit
RθJC	Thermal Resistance from Junction to Case		°C/W

Typical Characteristics







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